



NPN MEDIUM POWER TRANSISTORS IN SOT223

Features

- BV_{CEO} > 45V, 60V & 80V
- I_C = 1A High Continuous Collector Current
- I_{CM} = 2A Peak Pulse Current
- 2W Power Dissipation
- Low Saturation Voltage V_{CE(sat)} < 500mV @ 0.5A
- Gain Groups 10 and 16
- Complementary PNP Types: BCP51, 52 and 53
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound.
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208³
- Weight: 0.112 grams (approximate)

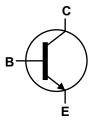
Applications

- Medium Power Switching or Amplification Applications
- AF Driver and Output Stages

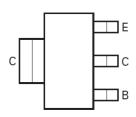




Top View



Device Symbol



Top View Pin-Out

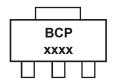
Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
BCP54TA	AEC-Q101	BCP 54	7	12	1,000
BCP5410TA	AEC-Q101	BCP 5410	7	12	1,000
BCP5416TA	AEC-Q101	BCP 5416	7	12	1,000
BCP5416QTA	Automotive	BCP 5416	7	12	1,000
BCP55TA	AEC-Q101	BCP 55	7	12	1,000
BCP5510TA	AEC-Q101	BCP 5510	7	12	1,000
BCP5516TA	AEC-Q101	BCP 5516	7	12	1,000
BCP56TA	AEC-Q101	BCP 56	7	12	1,000
BCP5610TA	AEC-Q101	BCP 5610	7	12	1,000
BCP5616TA	AEC-Q101	BCP 5616	7	12	1,000
BCP5616TC	AEC-Q101	BCP 5616	13	12	4,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product compliance definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html

Marking Information



BCP = Product Type Marking Code, Line 1. XXXX = Product Type Marking Code, Line 2 as follows:

BCP54 = 54 BCP55 = 55 BCP56 = 56 BCP5410 = 5410 BCP5510 = 5510 BCP5610 = 5610 BCP5416 = 5416 BCP5516 = 5516 BCP5616 = 5616



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	BCP54	BCP55	BCP56	Unit
Collector-Base Voltage	V _{CBO}	45	60	100	V
Collector-Emitter Voltage	V _{CEO}	45	60	80	V
Emitter-Base Voltage	V _{EBO}		V		
Continuous Collector Current	I _C		Α		
Peak Pulse Collector Current	I _{CM}				
Continuous Base Current	I _B	100			mA
Peak Pulse Base Current	I _{BM}	200			

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 6)	P _D	2	W
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	62	°C /W
Thermal Resistance, Junction to Leads (Note 7)		$R_{\theta JL}$	19.4	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C	

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

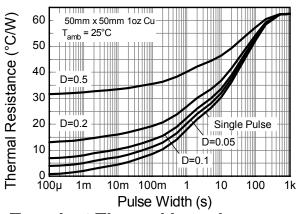
^{6.} For a device mounted with the collector lead on 50mm x 50mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.

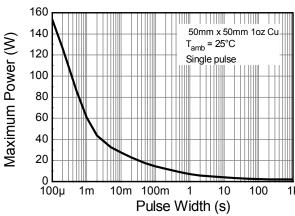
7. Thermal resistance from junction to solder-point (at the end of the collector lead).

8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



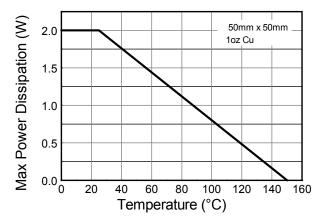
Thermal Characteristics and Derating Information





Transient Thermal Impedance

Pulse Power Dissipation



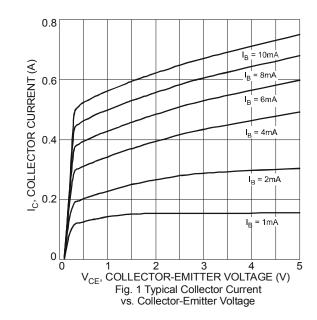
Derating Curve

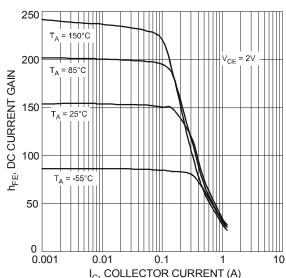


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

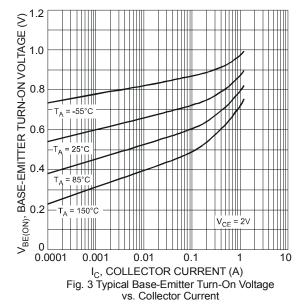
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Base	BCP54		45				
Breakdown Voltage	BCP55	BV _{CBO}	60	-	-	V	$I_{C} = 100 \mu A$
Breakdown voltage	BCP56		100				
Collector-Emitter	BCP54		45				
Breakdown Voltage (Note 9)	BCP55	BV _{CEO}	60	-	-	V	$I_C = 10mA$
Breakdown Voltage (Note 9)	BCP56		80				
Emitter-Base Breakdown Voltage		BV _{EBO}	5	-	-	V	$I_E = 10\mu A$
Collector Cut-off Current					0.1	μA	V _{CB} = 30V
Collector Cut-off Current		I _{CBO}	-	-	20	μA	$V_{CB} = 30V, T_A = +150^{\circ}C$
Emitter Cut-off Current		I _{EBO}	-	-	20	nA	V _{EB} = 4V
			25	-	-		I _C = 5mA, V _{CE} = 2V
	All versions		40	-	250	_	$I_C = 150 \text{mA}, V_{CE} = 2 \text{V}$
Static Forward Current Transfer Ratio (Note 9)		h_{FE}	25	-	-		$I_C = 500 \text{mA}, V_{CE} = 2 \text{V}$
	10 gain grp		63	-	160		$I_C = 150 \text{mA}, V_{CE} = 2 \text{V}$
	16 gain grp		100	-	250		$I_C = 150 \text{mA}, V_{CE} = 2 \text{V}$
Collector-Emitter Saturation Voltage (Note 9)		V _{CE(sat)}	-	-	0.5	V	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$
Base-Emitter Turn-On Voltage (Note 9)		V _{BE(on)}	-	-	1.0	V	I _C = 500mA, V _{CE} = 2V
Transition Frequency		f⊤	150	-	-	MHz	I_C = 50mA, V_{CE} = 10V f = 100MHz
Output Capacitance		Cobo	-	-	25	pF	V _{CB} = 10V, f = 1MHz

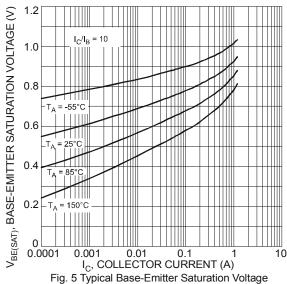
Notes: 9. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.

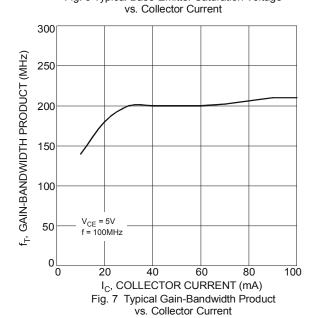












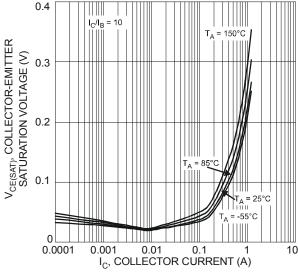


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

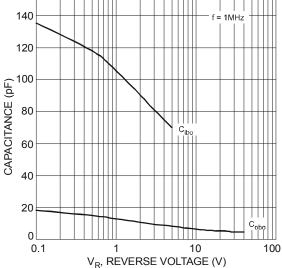
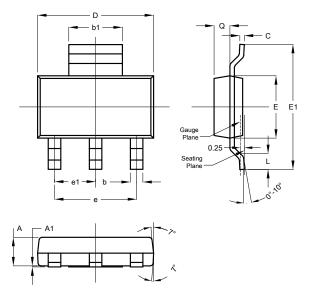


Fig. 6 Typical Capacitance Characteristics



Package Outline Dimensions

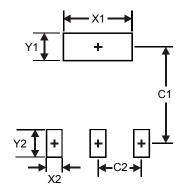
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT223						
Dim	Min	Max	Тур			
Α	1.55	1.65	1.60			
A1	0.010	0.15	0.05			
b	0.60	0.80	0.70			
b1	2.90	3.10	3.00			
С	0.20	0.30	0.25			
D	6.45	6.55	6.50			
E	3.45	3.55	3.50			
E1	6.90	7.10	7.00			
е	-	-	4.60			
e1	-	-	2.30			
L	0.85	1.05	0.95			
Q	0.84	0.94	0.89			
All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)			
X1	3.3			
X2	1.2			
Y1	1.6			
Y2	1.6			
C1	6.4			
C2	2.3			



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